

Power Supply Design Seminar

Practical EMI Considerations for Low-Power AC/DC Supplies

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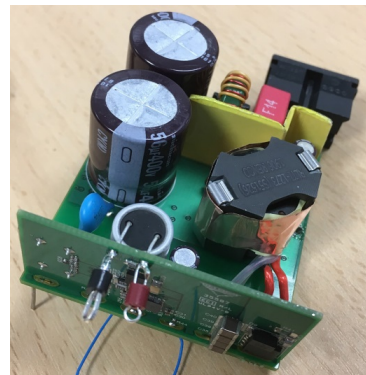
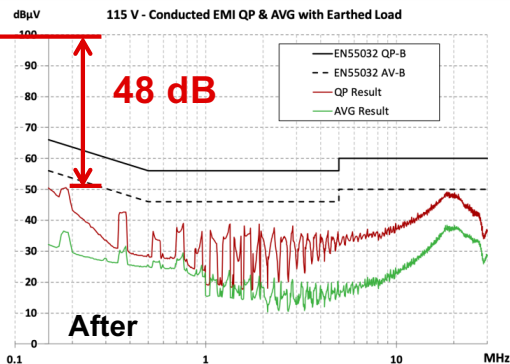
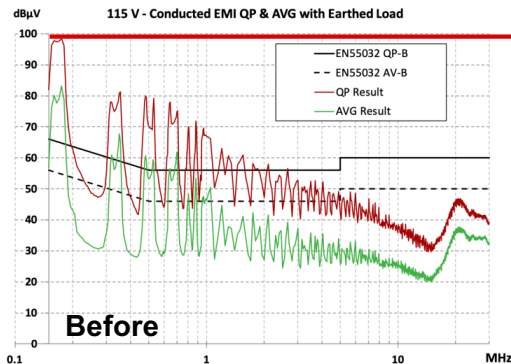
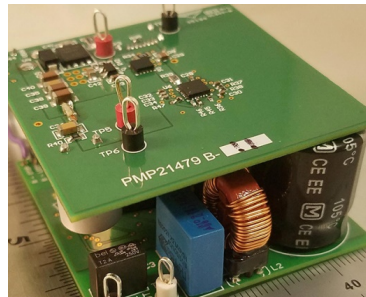
Practical EMI Considerations for Low-Power AC/DC Supplies

Bernard Keogh

Joe Leisten

Electromagnetic interference (EMI)

- I built my 65 W adapter prototype and resolved all functional issues
- I ran first-pass EMI scan – and my design failed – badly! ~ 100 dB μ V
 - *How can I fix the EMI?*
 - *Where do I start?*
- This presentation will show how to get to a result like this, without necessarily adding a big EMI filter



Agenda

- Introduction to EMI testing
- What causes EMI
- Differential-mode vs common-mode EMI
- EMI mitigation options
- Analyzing the transformer
- Troubleshooting & debug
- 65 W USB-PD example design using active clamp flyback (ACF) topology

Conducted emissions (CE) standards

- Summary of main product standards for conducted emissions

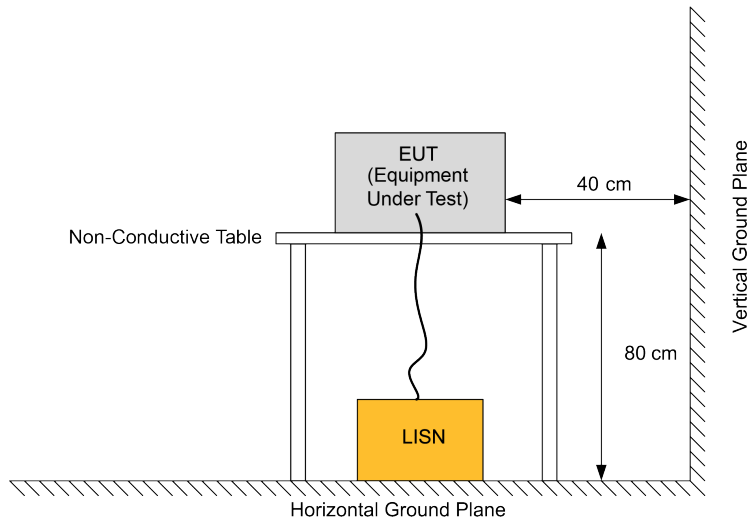
Product Sector	CISPR Standard	EN Standard	FCC Standard
Automotive	CISPR 25	EN 55025	--
Multimedia	CISPR 32	EN 55032	Part 15
ISM	CISPR 11	EN 55011	Part 18
Household appliances, electric tools and similar apparatus	CISPR 14-1	EN 55014-1	--
Lighting equipment	CISPR 15	EN 55015	Part 15/18

Reference:

Timothy Hegarty, "An overview of conducted EMI specifications for power supplies," <http://www.ti.com/lit/wp/slyy136/slyy136.pdf>

How conducted EMI is measured

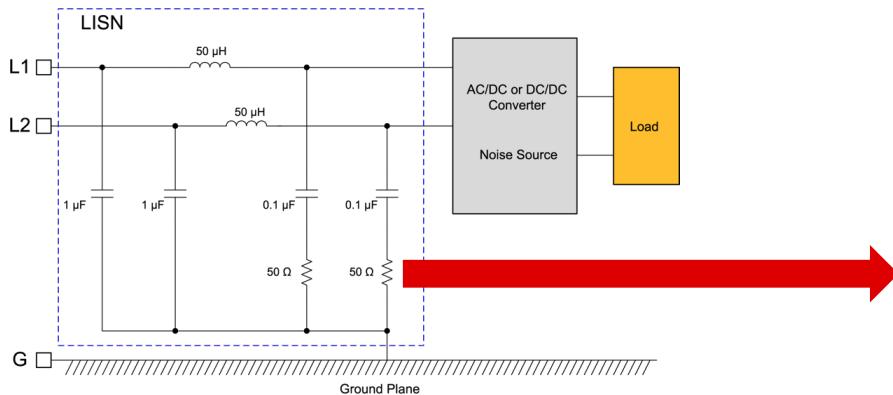
- Equipment under test (EUT) placed on non-conductive table
- Horizontal & vertical ground planes
 - Or screened room
- EUT powered through line impedance stabilization network (LISN)
- Measure high-frequency (HF) emissions from LISN



[1] EN55022, 2010, "Information technology equipment – Radio disturbance characteristics – Limits and methods of measurement"

LISN – Line impedance stabilization network

- Presents stable, consistent & repeatable line source impedance
- Separation of power source noise current for measurement
 - *Low frequency power current passes straight through from AC source*
- **“Total”** noise levels measured separately on **L1** (live) and **L2** (neutral)

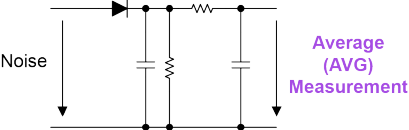
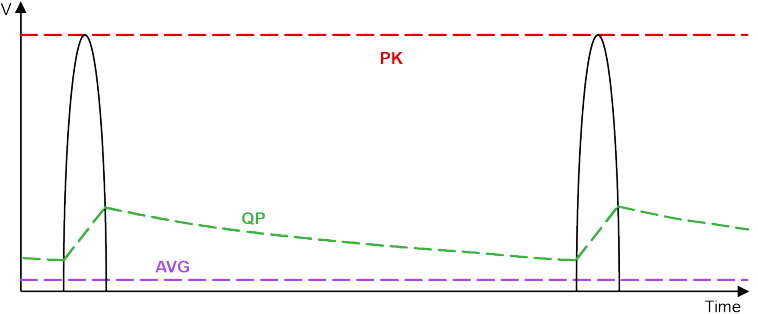
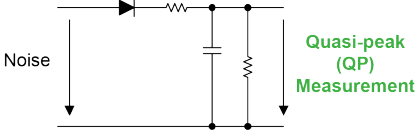
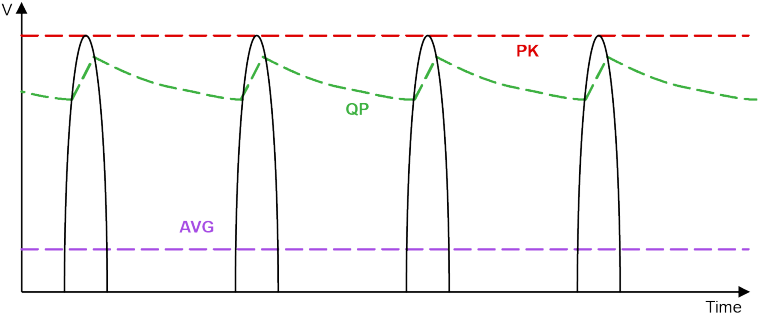
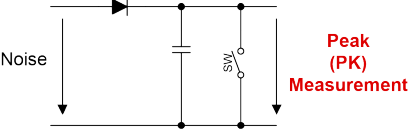


EMI Receiver



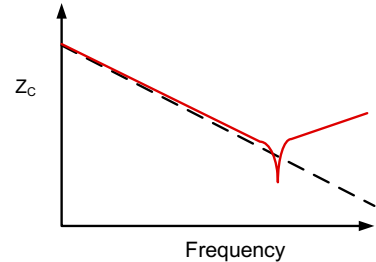
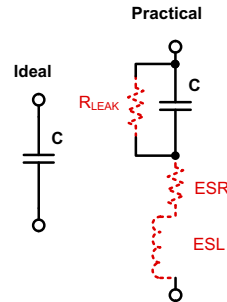
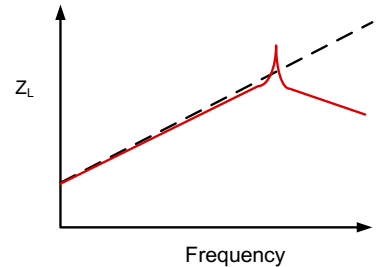
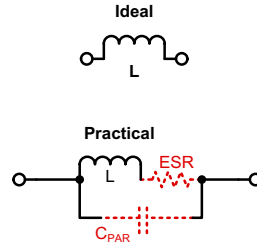
** Functional equivalent circuit of a LISN, not a complete schematic **

EMI receiver – Built-in detector types

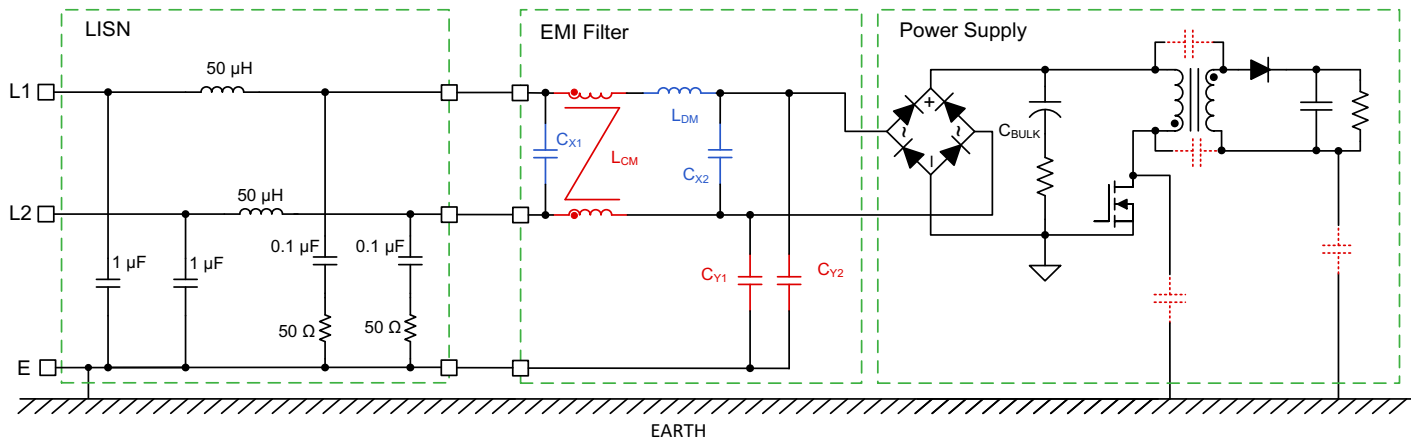


Component parasitics

- Parasitic elements are the **dominant cause** of EMI issues
- EMI noise is **coupled & propagated** through parasitic elements:
 - Capacitive coupling
 - Inductive coupling
- EMI filter performance is **dominated** by parasitic elements at higher frequency:
 - Parasitic capacitance of inductors
 - Parasitic inductance of capacitors



LISN + EMI filter + power supply



LISN – measures noise

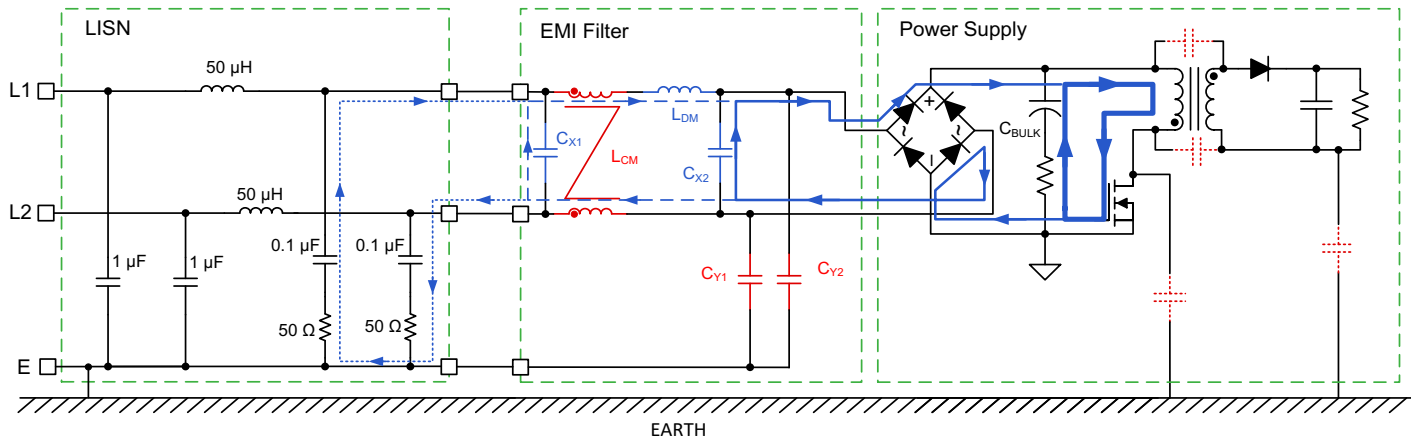
EMI filter – limits noise
that gets to the LISN

(*CM – red, DM – blue*)

Power supply – generates the
noise

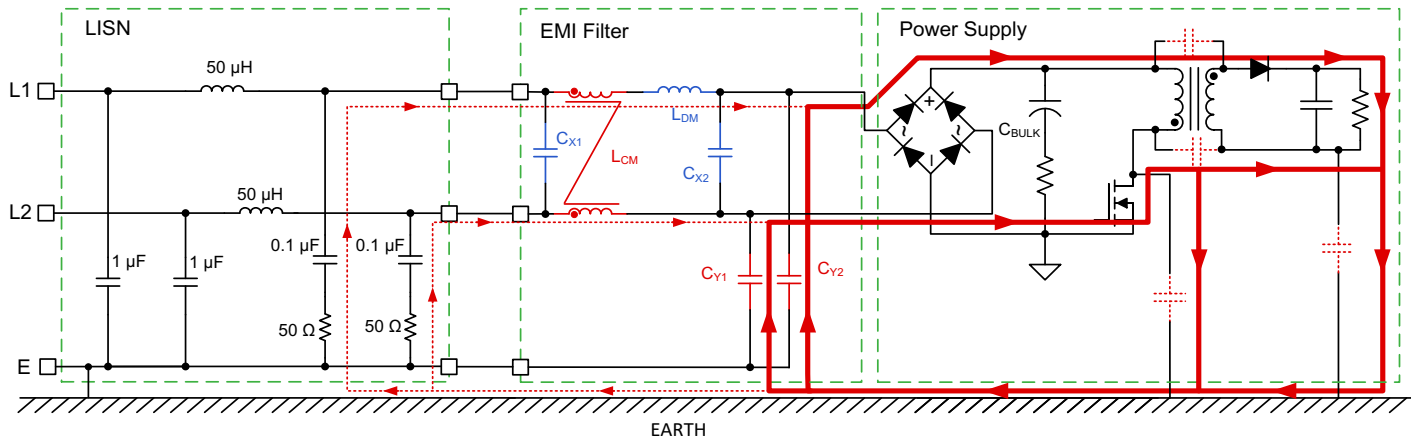
(*parasitic cap – red dotted*)

DM EMI filter and current path



- DM EMI filter limits DM noise that gets to the LISN
 - X-caps divert current away from LISN, keep local to power supply
 - DM choke high impedance reduces size of current flowing to LISN

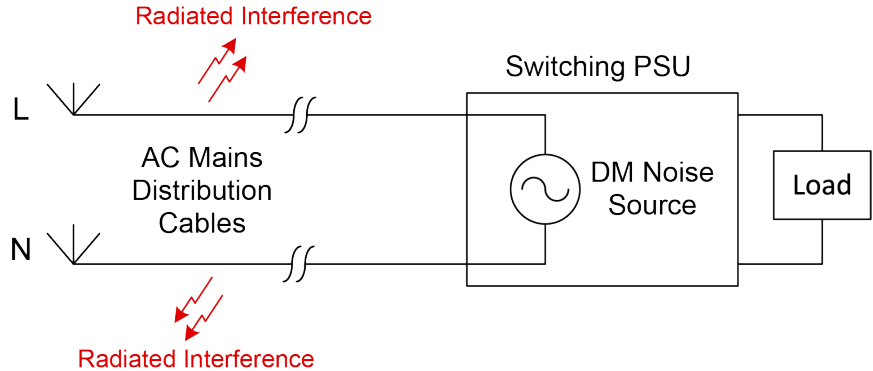
CM EMI filter and current path



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 - Y-caps divert current away from LISN, keep local to the power supply
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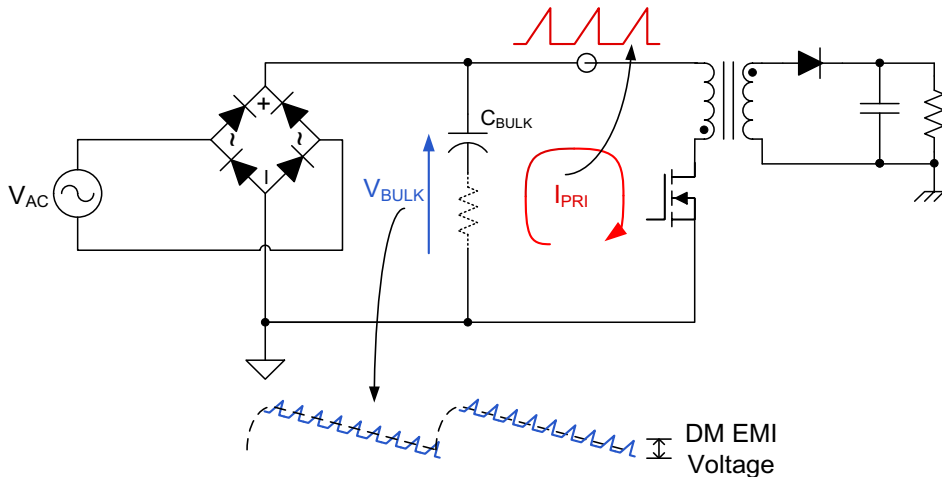
Why care about differential-mode (DM) EMI?

- DM noise conducts to the AC utility supply network
- Long AC distribution cables – act as good dipole antenna
- Will inadvertently radiate switching noise and interfere with radio communications
 - (E.g., noise @ ~100 MHz will affect FM radio)



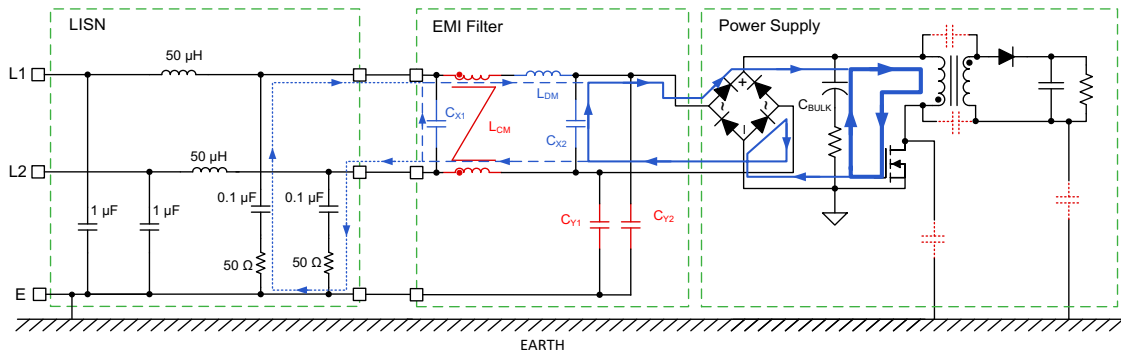
How is DM EMI generated?

- Switching ripple current produces ripple voltage across ESR (& ESL)
- Ripple voltage is the DM noise that needs to be attenuated/filtered



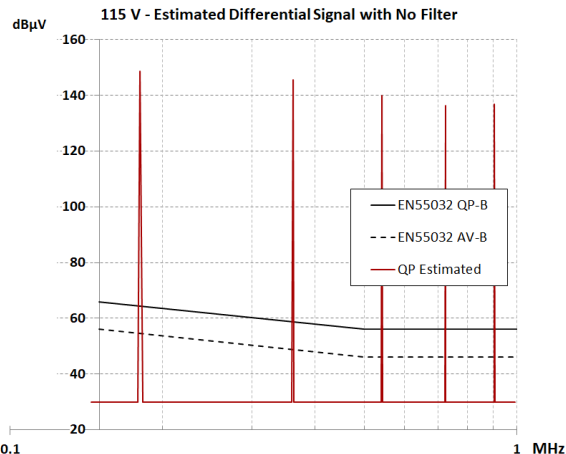
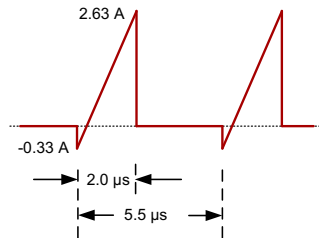
Mitigation options for DM noise

- Include EMI at the design phase
 - Make design & component choices to minimize DM EMI signal amplitude
 - Chose frequency, inductance, etc. to minimize PK-PK ripple current
 - Choose capacitors with low ESR to minimize PK-PK ripple voltage
 - Good PCB layout important to minimize EMI
- Design sufficient DM LC filter to reduce the ripple that gets onto the AC line input



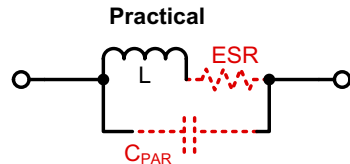
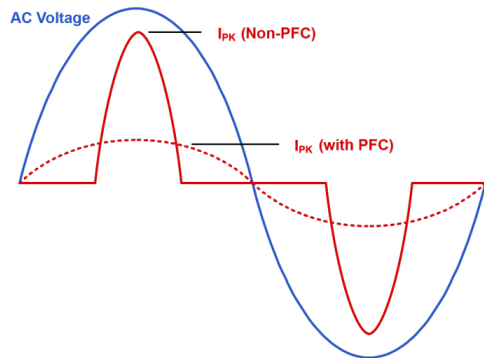
DM filter design methodology

- Measure, simulate or calculate time-domain current waveform
- Fourier analysis of time-domain switching current
 - *Convert waveform into harmonic components*
- Establish required attenuation at each frequency
 - *To get sufficient margin below the required EMI limit*
- Design the DM filter to achieve required attenuation
 - *Need to check all frequencies of interest*
 - *Typically limited by lowest frequency inside measurement band*
 - *Typically EMI starts at 150 kHz for AC/DC PSU to meet EN55022 or EN55032*



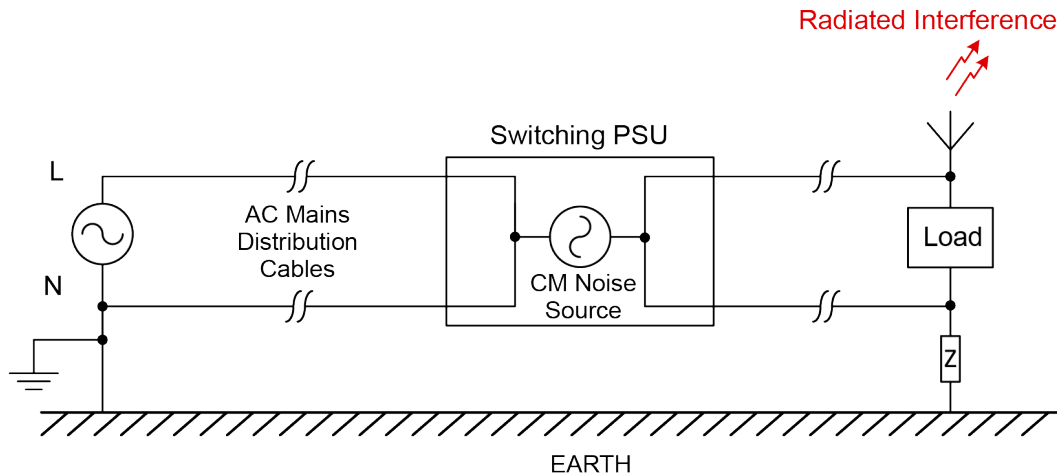
DM filter choke practical considerations

- Choke requires high attenuation over wide bandwidth:
 - Load current amplitude typically several amps
 - At 50 dB μ V, current in LISN 50 Ω resistor only $\sim 6.3 \mu$ A
- Beware inductance roll-off with DC-bias
 - Must not saturate to be effective – needs high current rating
 - Consider the peak line current for non-PFC – high crest factor
- Switching power stage has fast changing magnetic fields
 - Beware filter bypassing & noise coupling
- Parasitic capacitance across DM inductor very important
 - Reduces effectiveness, especially at high frequency
- Example: To filter 300 kHz component, typically set LC freq. ~ 30 kHz
 - Expect ~ 40 dB attenuation at 300 kHz (double-pole $\Rightarrow 40$ dB/decade)
 - With parasitic cap \Rightarrow more like 30 dB attenuation only – even worse at higher frequency



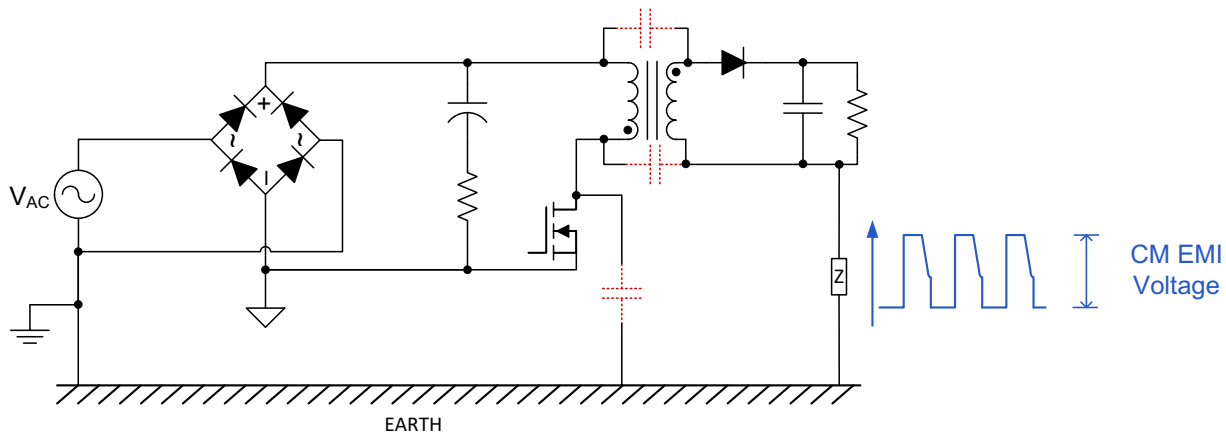
Why care about common-mode (CM) EMI?

- Again, AC distribution cables and output load cables act as good uni-polar antenna
- CM noise will radiate from the cables and interfere with radio communications



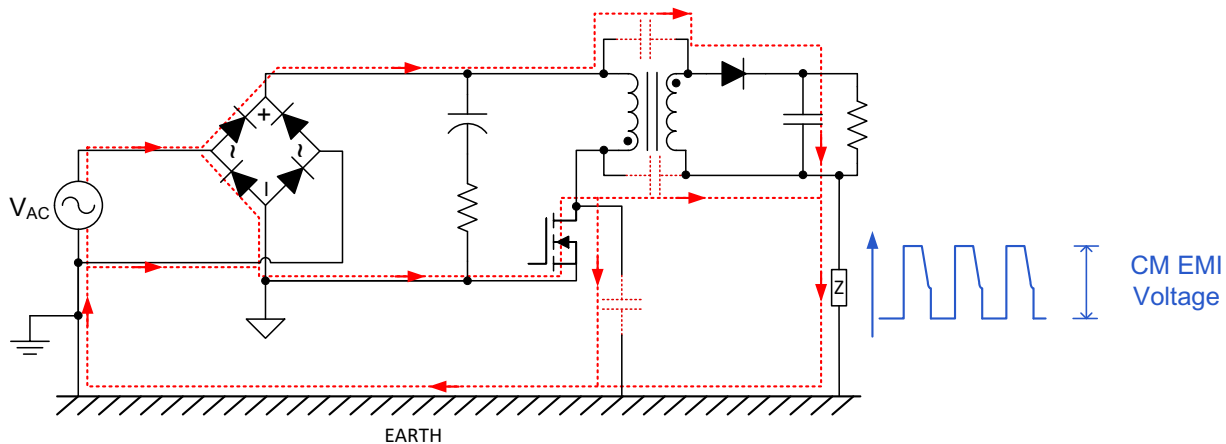
How is CM EMI generated?

- Switching voltage across parasitic capacitance causes CM current flow to EARTH



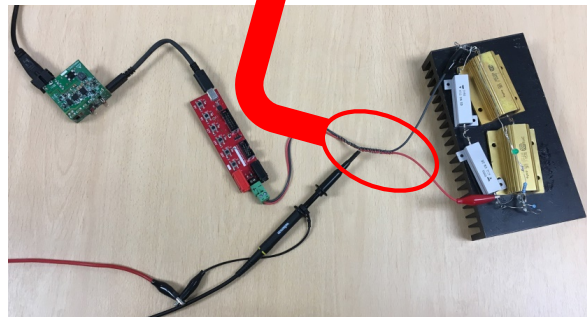
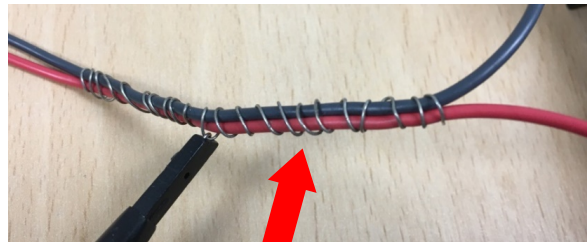
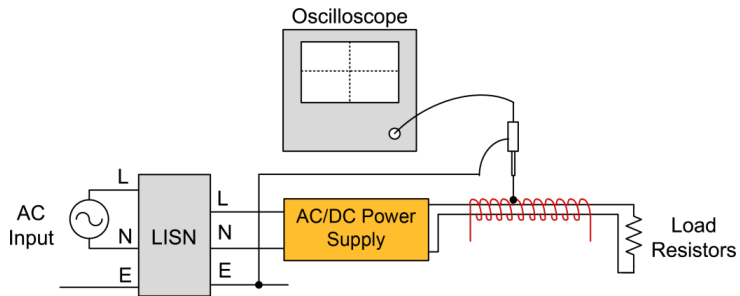
How is CM EMI generated?

- Switching voltage across parasitic capacitance causes CM current flow to EARTH
- CM noise also radiated to other circuit nodes



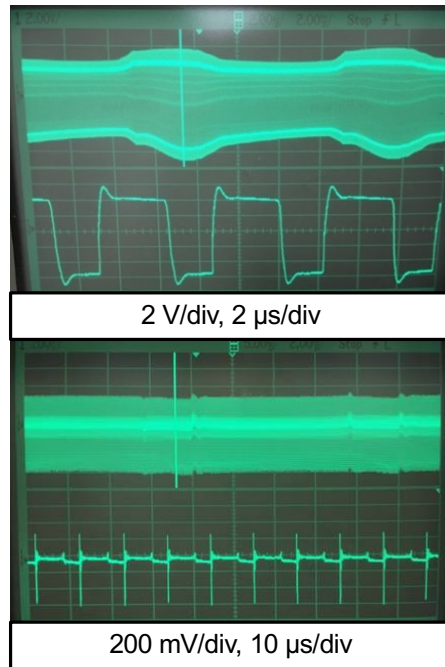
Observing the time-domain CM signal at the output

- Useful debug technique – ball-park indication of CM performance
 - Remove Y-cap temporarily (maximize signal)
 - Power EUT through LISN, with resistor loads
 - Wind several turns of wire around the load cables to create capacitive sensing coil (pickup coil)
 - Connect scope EARTH lead to LISN EARTH
 - Connect scope tip to sensing coil
 - Scope plot shows how much CM is coupled to output



Interpretation of time-domain CM signal

- Will see “switch-node” shaped waveform – coupled to output
- Large PK-PK amplitude \Rightarrow bad CM noise
 - Will require significant CM filtering to suppress
 - Result from ACF example with 100 dB μ V EMI
- Small PK-PK amplitude \Rightarrow good CM noise
 - “Balanced” structure giving low CM
 - Will require much smaller CM filter
- Residual HF “spikes” \Rightarrow should only need small HF CM choke



Mitigation options for CM noise

1. Shielding:

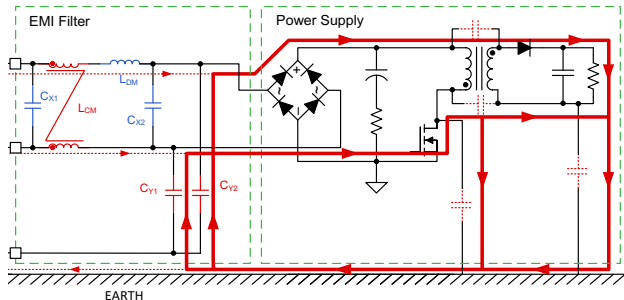
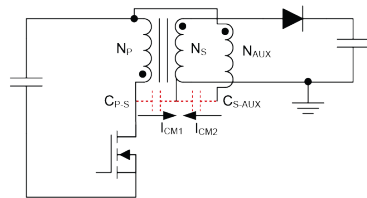
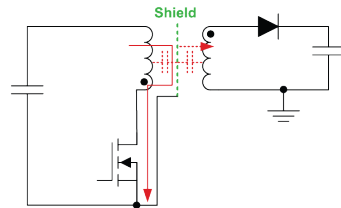
- Reduce flow of HF current to EARTH

2. Cancellation:

- Arrange transformer and power stage for balanced CM

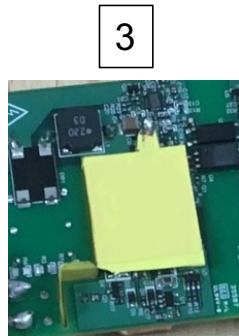
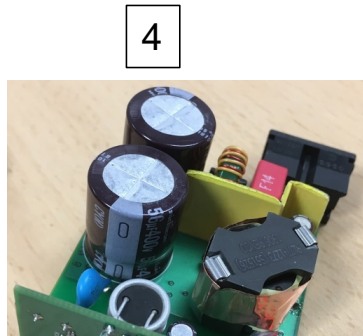
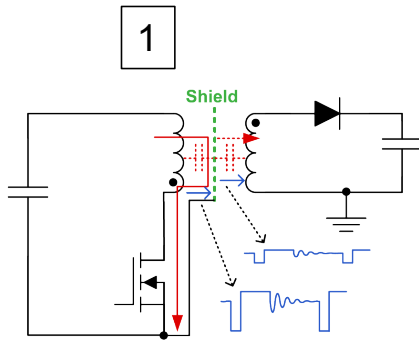
3. Filtering:

- Increase impedance of the EARTH return path
- Provide alternative routes for the HF current



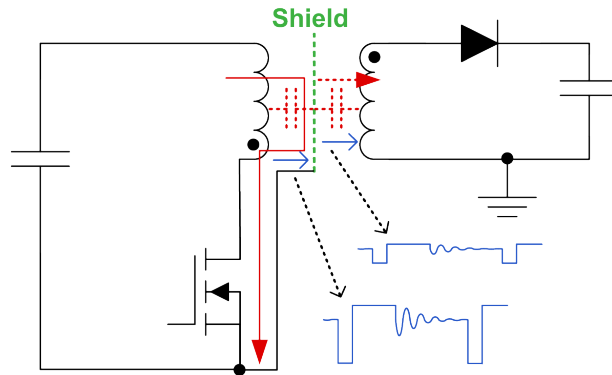
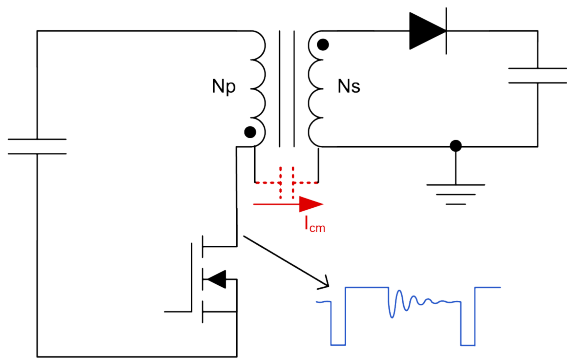
1. CM mitigation by shielding

1. Shielding inside the transformer
 - Internal shields between pri & sec
2. Shielding outside the transformer
 - GNDed flux-band
3. Shielding of noisy circuit nodes
 - GNDed heatsinks over/around high-voltage switching nodes
4. Shielding of EMI filter from switching cct.
 - GNDed shields/enclosures around filter



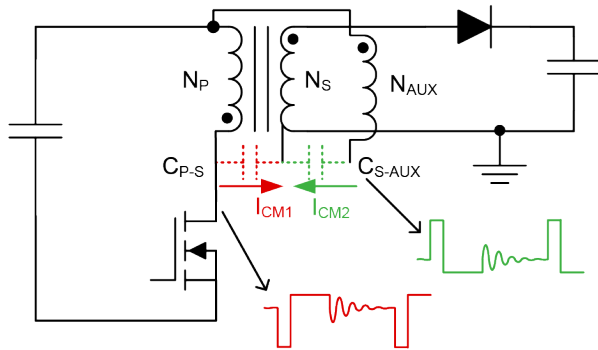
Transformer internal shielding

- Shield added to keep most of CM current local to primary
- Shield is 1-turn winding \Rightarrow lower induced voltage, less voltage across parasitic capacitance between shield & sec \Rightarrow less CM current flows
- Shield must be thin ($< 50 \mu\text{m}$) \Rightarrow minimize induced eddy current loss
 - *Eddy currents get very significant as F_{SW} increases*



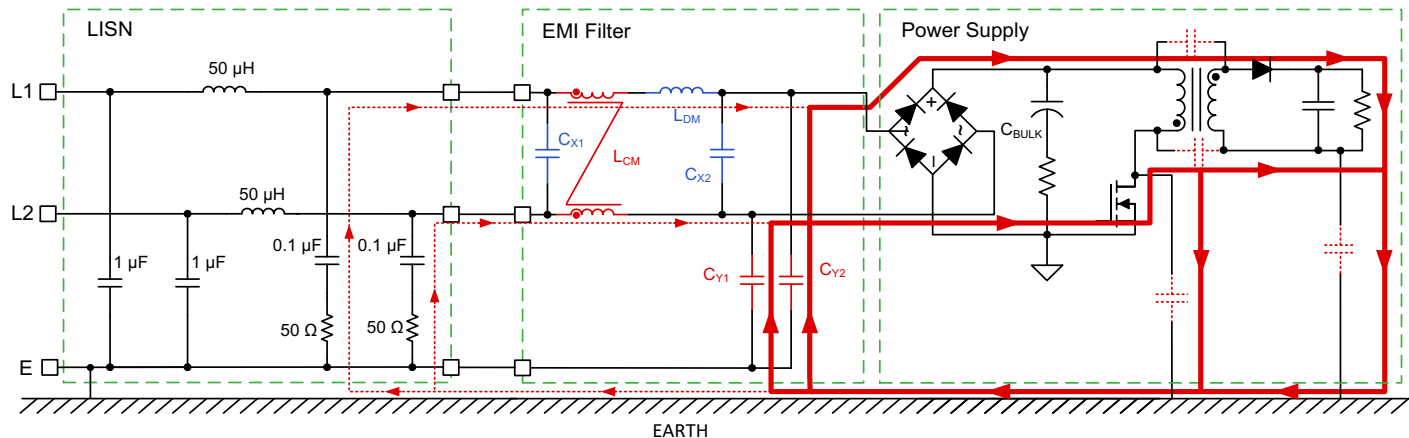
2. CM mitigation by cancellation/balance

- Single-ended topologies – can add explicit additional cancellation elements
 - Add auxiliary (AUX) transformer winding
 - AUX voltage proportional to CM waveform
 - Arrange AUX polarity for opposite phase
- Capacitor to inject cancelling current, I_{CM2} , to balance CM current from primary, I_{CM1}
- Injection capacitor explicit physical component added to design
- Or can use parasitic capacitance, e.g., C_{S-AUX} , part of transformer structure



3. CM mitigation by filtering

- CM filter uses high-impedance CM chokes and low-impedance Y-capacitors
- CM choke limits the flow of CM current from EARTH through the LISN
- Y-cap provides low impedance to keep CM current local to primary GND and away from LISN



CM filter choke practical considerations

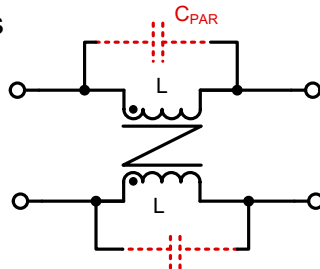
- **Frequency response of core material**
 - High- μ cores \Rightarrow high L value @ low freq, but roll off fast at higher freq
 - High-freq cores \Rightarrow low- μ , smaller L value @ low freq, better vs freq
 - Sometimes need to use 2 CM chokes, 1 for LF & 1 for HF
- **Split-wound vs bifilar-wound toroid**
 - Split-wound popular, lower cost, “free” DM choke from leakage field
 - Bifilar \Rightarrow 1-side insulated wire, higher cost, but better noise immunity
- **Parasitic input-output cap – multi-layer windings**
 - Parasitic cap depends on number of turns & layers
 - High C_{PAR} input-output cap \Rightarrow worse @ HF
 - Less layers \Rightarrow lower L, but also lower C_{PAR}
 - Sectional bobbins – used to reduce C_{PAR}



Split-Wound*



Bifilar-Wound*



Multi-Section

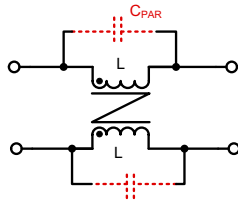
*CM choke 3-D images reproduced with permission of Würth Elektronik

CM filter choke – Impact of C_{PAR}



Split-Wound 2L

- Split-wound 2-layer:
 - 25T, 5.1 mH
 - Excess pass margin @ LF
 - Low pass margin @ 20 MHz



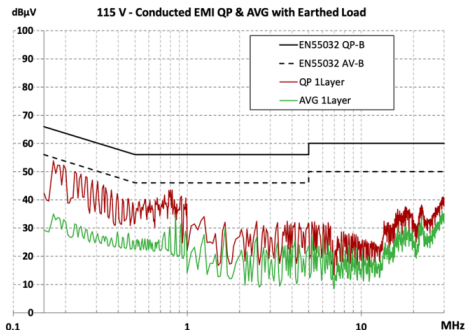
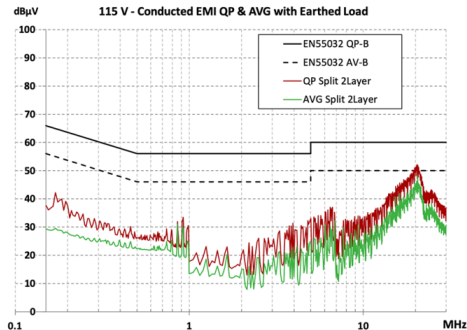
Bifilar-Wound 1L

- Bifilar-wound 1-layer:
 - 14T, 1.1 mH
 - Low input-output C_{PAR}
 - Lower L at LF, but better at HF
 - Better balance across frequency span



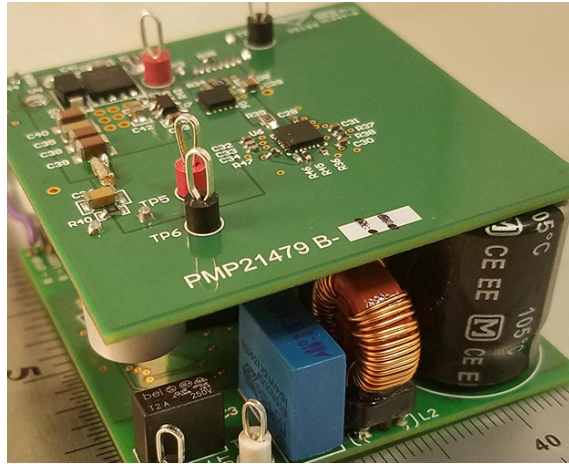
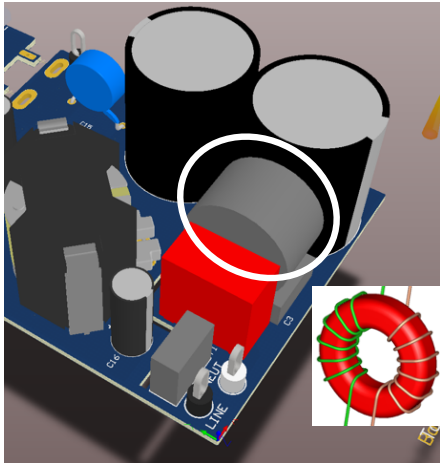
Split-Wound 1L

- Split-wound 1-layer:
 - 14T, 1.4 mH
 - Similar low input-output C_{PAR}
 - Similar result as bifilar-wound



CM choke example

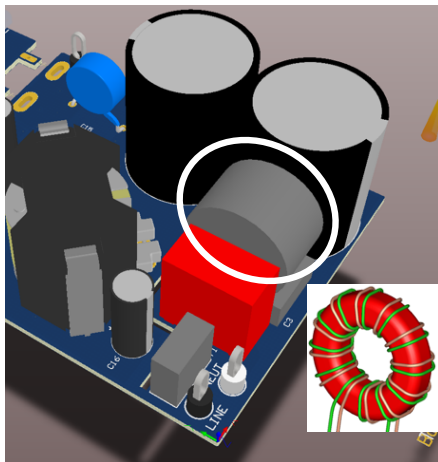
- Initial split-wound choke had issues due to asymmetric noise coupling from transformer
 - Shows up as big difference in EMI on L vs N



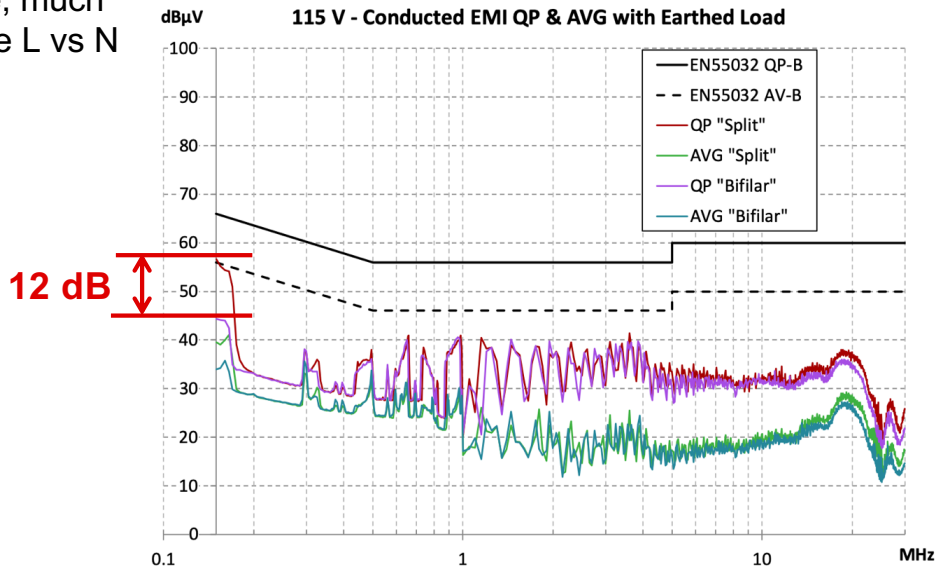
*CM choke 3-D image reproduced with permission of Würth Elektronik

CM choke example

- Changed to bifilar-wound choke, much better EMI result; less difference L vs N
- Much better noise immunity

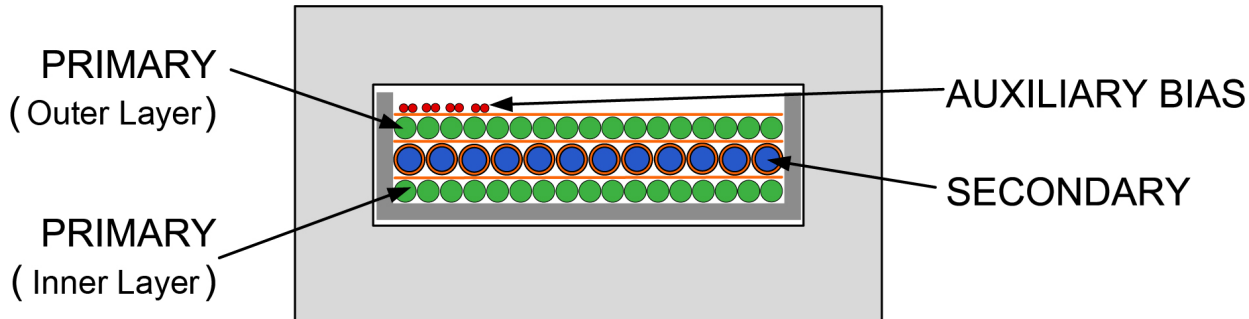


*CM choke 3-D image reproduced with permission of Würth Elektronik



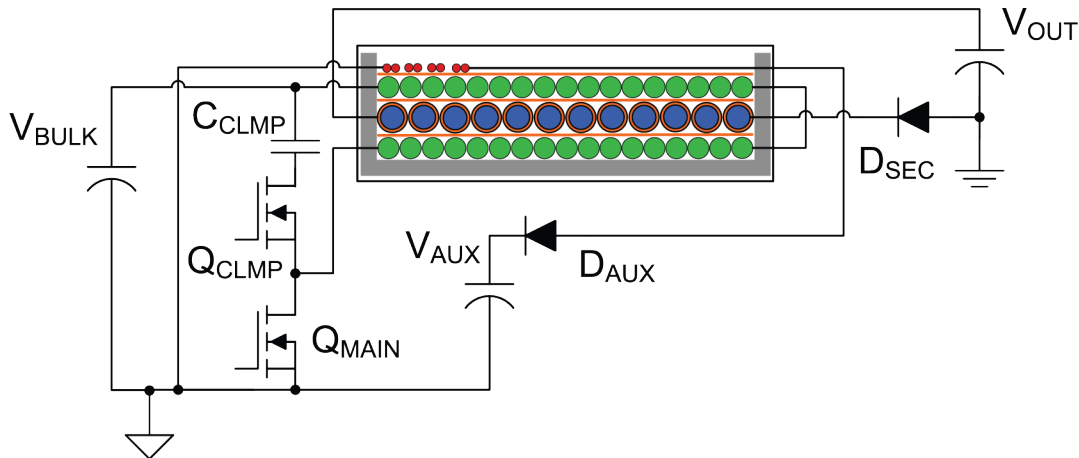
Transformer CM noise analysis – PMP21479 ACF

- Initial design – interleaved flyback transformer construction, no internal shielding
- Same transformer used for initial test with poor 100 dB μ V EMI result



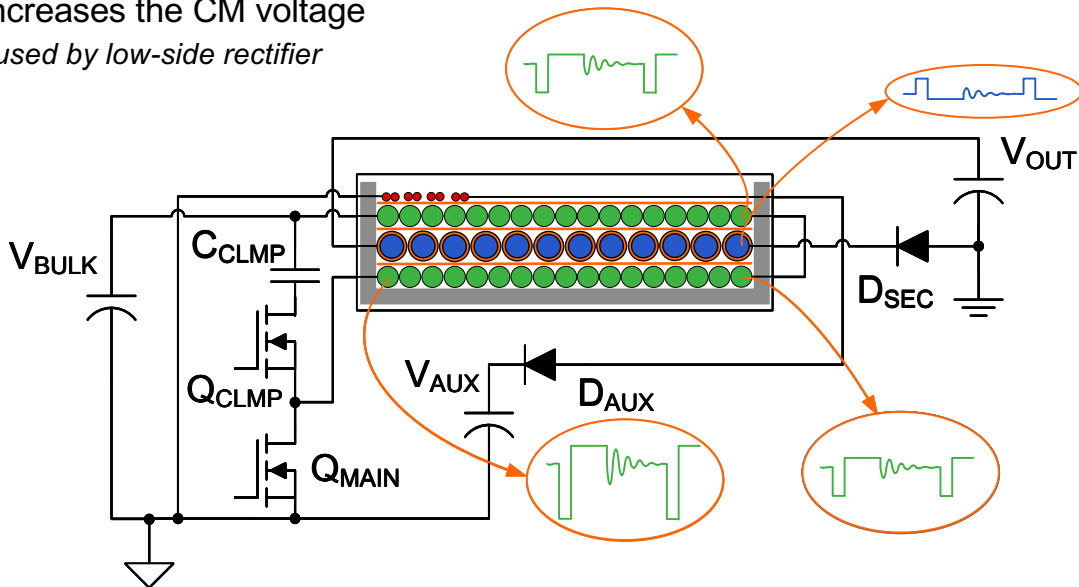
Transformer CM noise analysis – PMP21479 ACF

- Circuit connections to the ACF power stage
- Note the secondary low-side rectifier – causes inverted secondary winding polarity



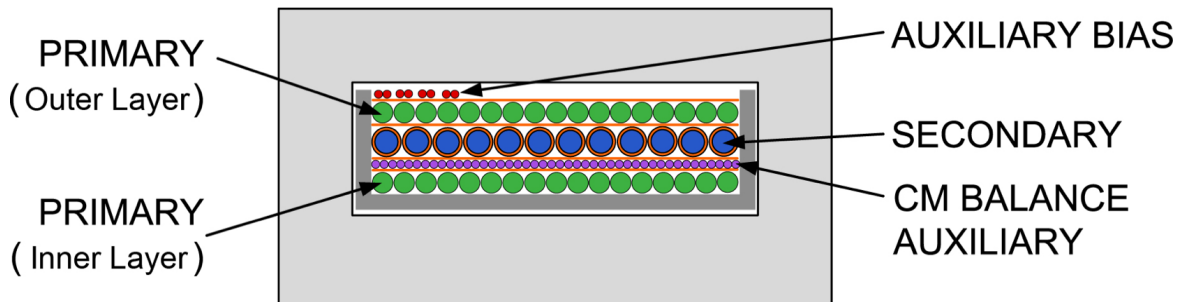
Transformer CM noise analysis – PMP21479 ACF

- Note that primary and secondary waveforms are inverse of each other
- This increases the CM voltage
 - *Caused by low-side rectifier*



Transformer CM balance – PMP21479 ACF

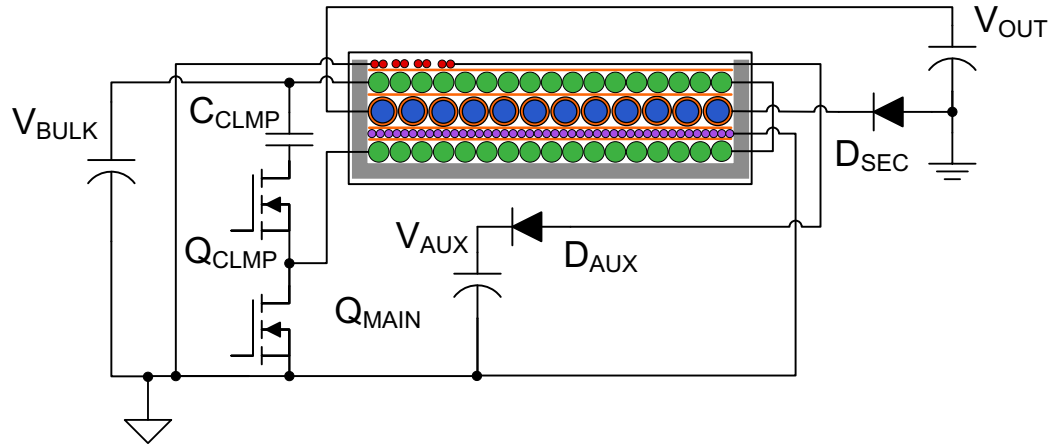
- Add CM balance auxiliary layer (purple) in-between inner PRI (noisier) to SEC interface:
 - *Fill layer completely – acts as shield between PRI & SEC*
 - *Add turns to create CM balance, inject current to balance other PRI-SEC interface*



- NOTE: this example shows one way to add CM balance
- But there are many different ways to achieve the same CM result

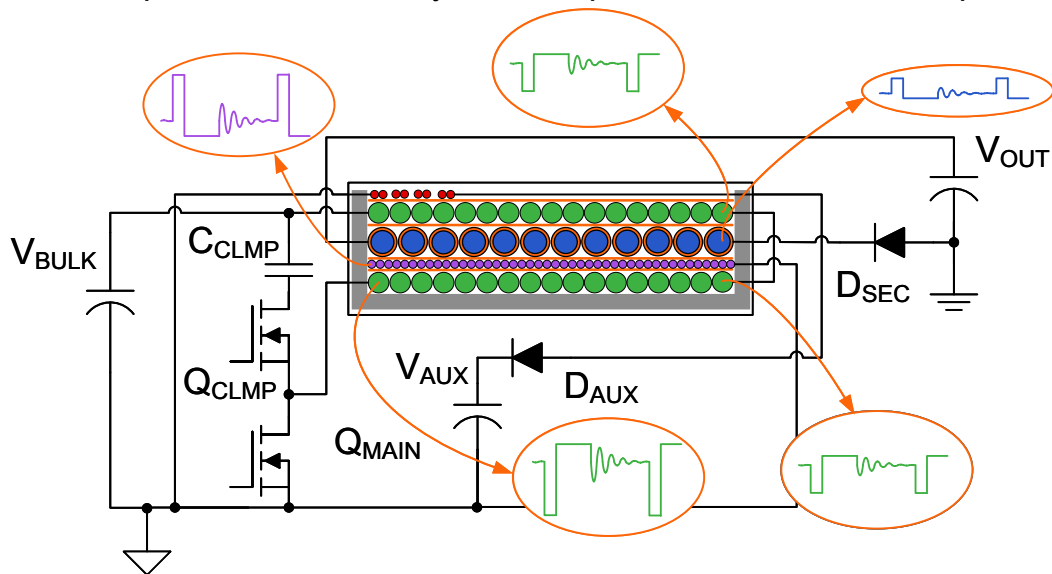
Transformer CM balance – PMP21479 ACF

- PRI, SEC & AUX bias connections same as before
- CM auxiliary layer starts at PRI GND, and winds in SAME direction as SEC



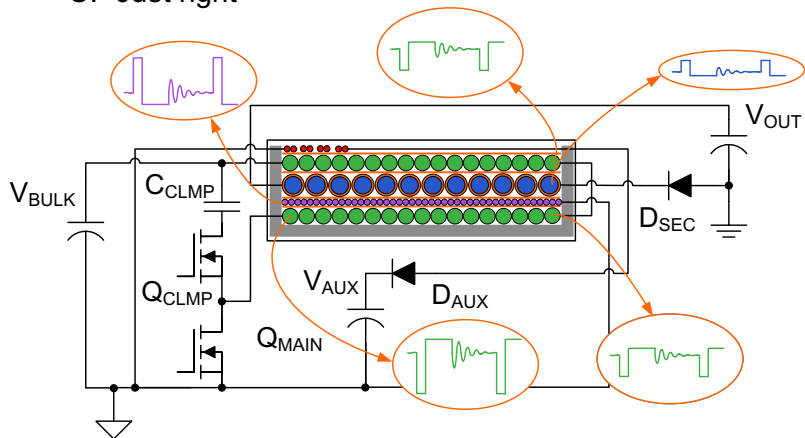
Transformer CM balance – PMP21479 ACF

- Waveforms – PRI & SEC same as before
- CM AUX – same phase as secondary – *but amplitude increased to compensate for outer PRI*

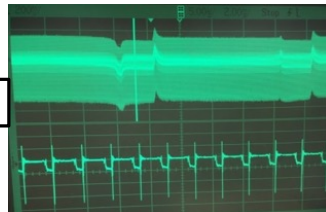


Transformer CM balance – PMP21479 ACF

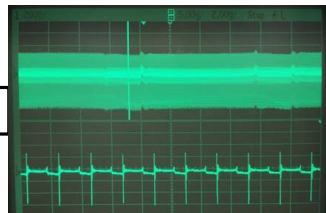
- CM AUX – need to adjust number of turns to balance the CM nulling
- Waveforms showing:
 - A: Slightly under-compensated
 - B: Slightly over-compensated
 - C: “Just right”



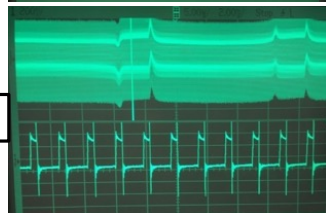
A: 0.2 V/div, 5 μ s/div



C: 0.2 V/div, 10 μ s/div

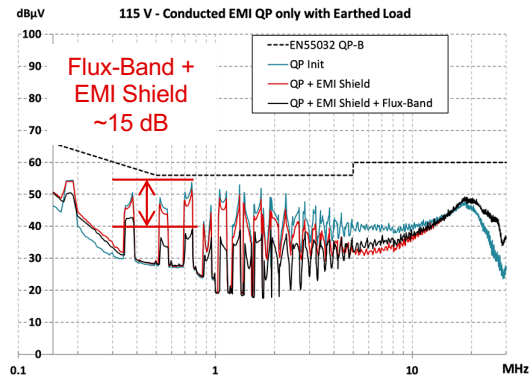
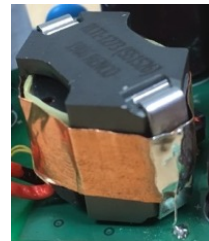
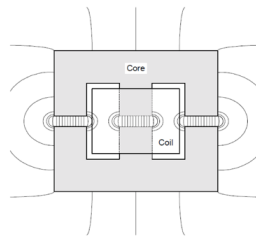


B: 0.2 V/div, 5 μ s/div



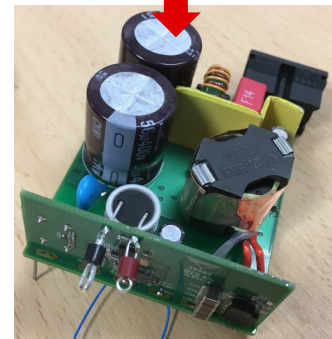
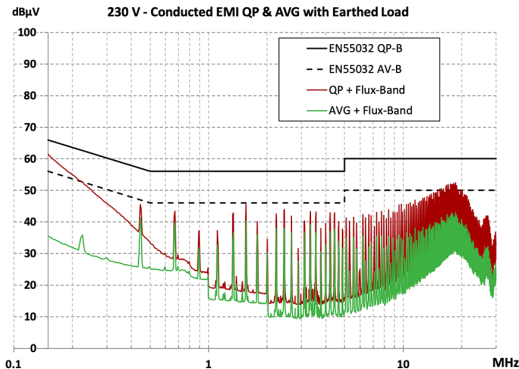
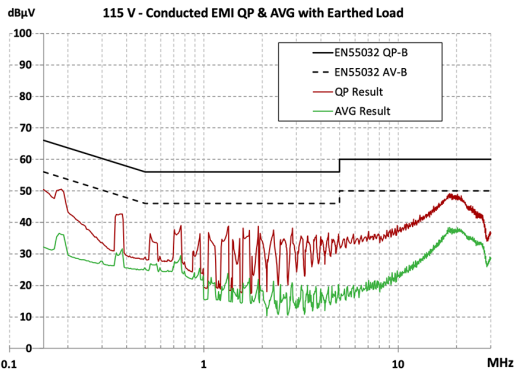
Transformer “housekeeping” best practices

- Center-leg air-gaps only – outer legs will radiate
- “Noisier” windings on inside of layer structure
- Tie ferrite core to local primary GND
 - GNDing & flux-banding can give >10 dB improvement!
- Interleaving trade-offs
 - Lower leakage inductance
 - Higher pri-sec parasitic capacitance, higher CM
- Be aware of internal construction
 - Average CM voltage across the pri-sec capacitance
 - Arrange winding layers to minimize voltage difference
 - *Minimizes CM current*



PMP21479 65 W ACF USB-PD – Final result

- Improve transformer structure, add CM balance/shield winding layer
- Add transformer grounding & flux-banding + EMI shield
- Improve CM choke to bifilar-wound type
- Improve output capacitor location, improve PCB orientation
 - Largely “low-cost” improvements
 - Small efficiency penalty (eddy loss in cancellation layer)



Summary & conclusions

- Consider EMI right from the start – inherent part of the power supply design
- Minimize DM & CM EMI noise at source
- DM filter can be designed/calculated/simulated more easily than CM
- CM balance is important – as much as practically possible
- Debug to establish if EMI issue is CM or DM or both
- Assess CM performance in time-domain – compare different transformers
- For isolated PSU, transformer is most important component
 - Internal construction details, CM balance, shielding, parasitic capacitance, housekeeping
- EMI filter components – be aware of parasitics and HF effects
- PCB layout and component placement – be aware of stray coupling paths

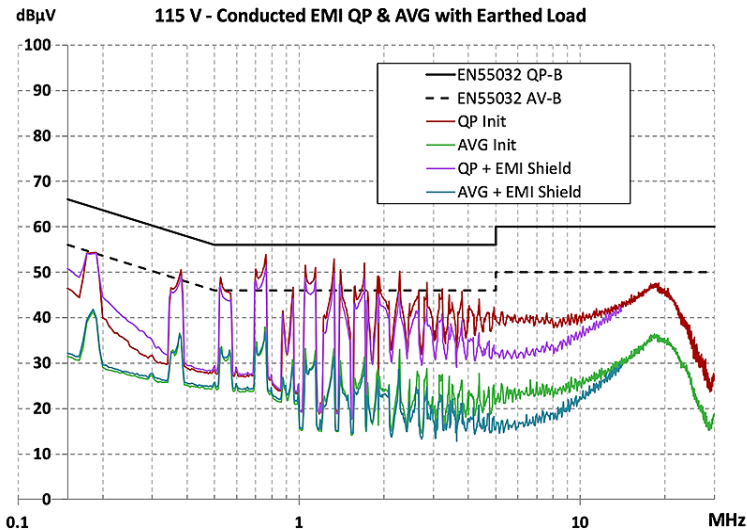
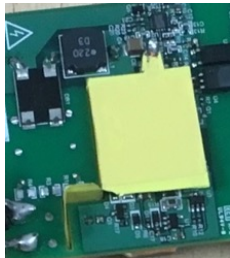
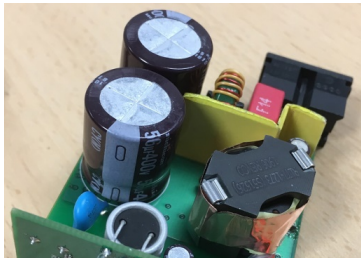
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PMP21479, Brian King, 2019.
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APPENDIX – BACK-UP SLIDES

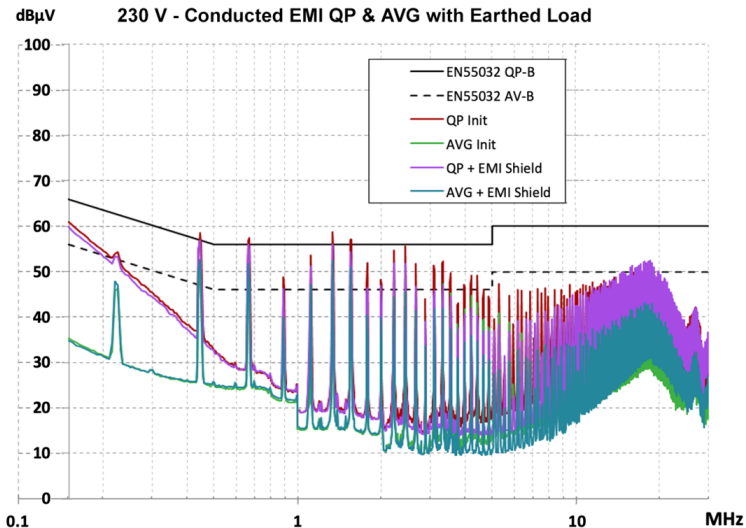
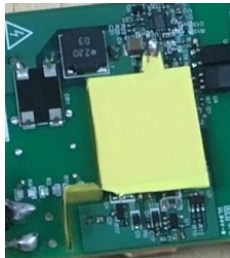
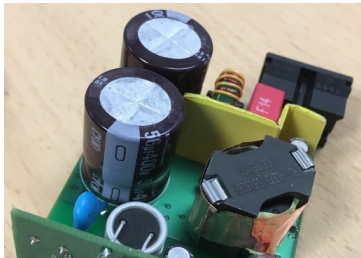
Transformer flux-band detailed results – 115 V

- EMI shield only (over switch-node and between EMI filter and transformer)
- NO flux-band, ferrite core floating
- Biggest improvement ~5-8 MHz



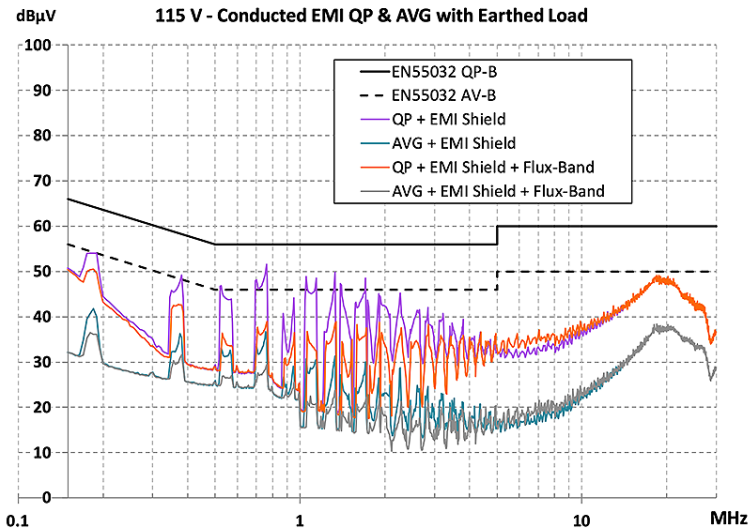
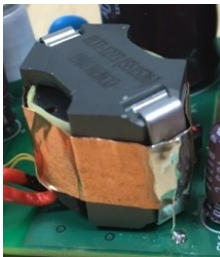
Transformer EMI shield detailed results – 230 V

- EMI shield only (over switch-node and between EMI filter and transformer)
- NO flux-band, ferrite core floating
- Biggest improvement ~3-8 MHz



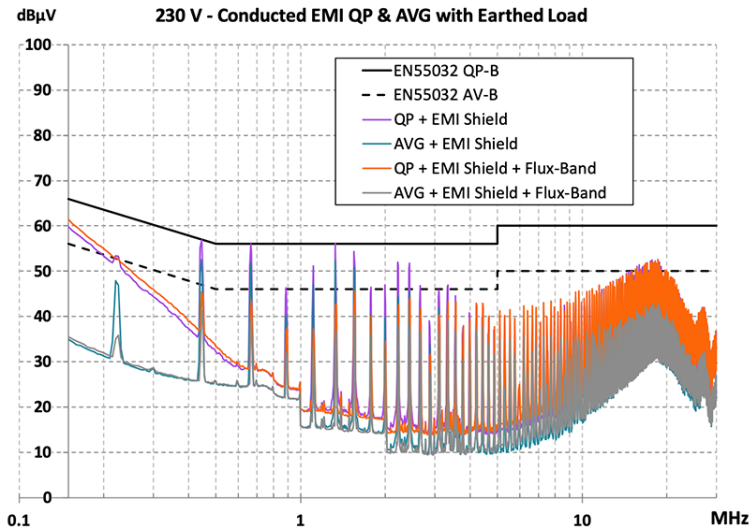
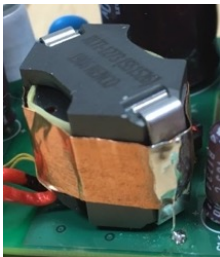
Transformer flux-band detailed results – 115 V

- EMI shield only (over switch-node and between EMI filter and transformer)
- Add flux-band, connected to local primary GND
- Much more significant reduction from 150 kHz to ~4 MHz



Transformer flux-band detailed results – 230 V

- EMI shield only (over switch-node and between EMI filter and transformer)
- Add flux-band, connected to local primary GND
- Much more significant reduction from 150 kHz to ~4 MHz
 - Especially for AVERAGE, which is much tougher at 230 V



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